NCV1009

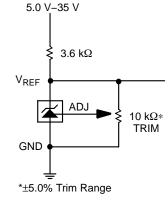
2.5 Volt Reference

The NCV1009 is a precision trimmed 2.5 V \pm 5.0 mV shunt regulator diode. The low dynamic impedance and wide operating current range enhances its versatility. The tight reference tolerance is achieved by on-chip trimming which minimizes voltage tolerance and temperature drift.

A third terminal allows the reference voltage to be adjusted $\pm 5.0\%$ to calibrate out system errors. In many applications, the NCV1009Z can be used as a pin-to-pin replacement of the LT1009CZ and the LM136Z-2.5 with the external trim network eliminated.

Features

- 0.2% Initial Tolerance Max.
- Guaranteed Temperature Stability
- Maximum 0.6 Ω Dynamic Impedance
- Wide Operating Current Range
- Directly Interchangeable with LT1009 and LM136 for Improved Performance
- No Adjustments Needed for Minimum Temperature Coefficient
- Meets Mil Std 883C ESD Requirements
- Extended Operating Temperature Range for Use in Automotive Applications
- NCV Prefix, for Automotive and Other Applications Requiring Site and Change Control
- Pb–Free Packages are Available



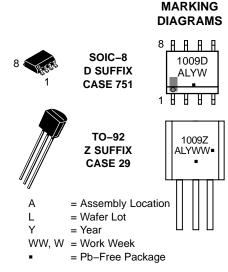
If the external trim resistor is not used, the "ADJ. PIN" should be left floating. The 10k trim potentiometer does not effect the temperature coefficient of the device.

Figure 1. Application Diagram

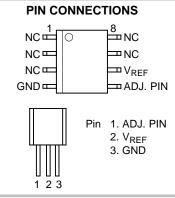


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(Note: Microdot may be in either location)

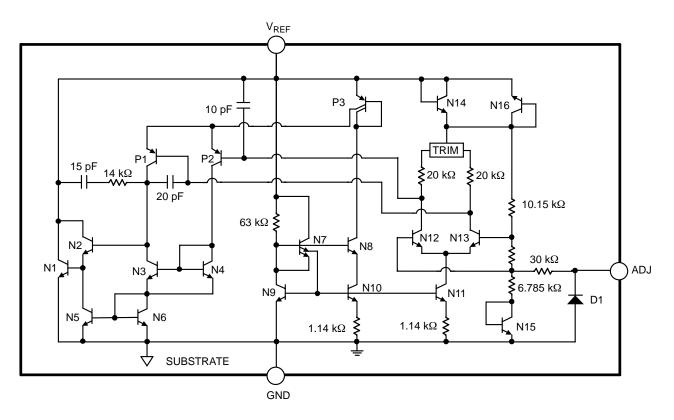


ORDERING INFORMATION

Device	Package	Shipping
NCV1009D	SOIC-8	95 Units/Rail
NCV1009DR2	SOIC-8	2500 Tape & Reel
NCV1009DR2G	SOIC-8 (Pb-Free)	2500 Tape & Reel
NCV1009Z	TO-92	2000 Units/Rail
NCV1009ZG	TO-92 (Pb-Free)	2000 Tape & Reel

⁺For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NCV1009





MAXIMUM RATINGS*

Rating	Value	Unit
Reverse Current	20	mA
Forward	10	mA
Package Thermal Resistance, SOIC–8: Junction–to–Case, $R_{\theta JC}$ Junction–to–Ambient, $R_{\theta JA}$ Package Thermal Resistance, TO–92: Junction–to–Case, $R_{\theta JC}$ Junction–to–Ambient, $R_{\theta JA}$	45 165 - 170	°C/W °C/W °C/W °C/W
Operating Temperature Range	-40 to +125	°C
Storage Temperature Range	-65 to +150	°C
Lead Temperature Soldering: Wave Solder (through hole styles Reflow: (SMD styles on		°C ℃

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected. *The maximum package power dissipation must be observed.

1. 10 second maximum

2. 60 second maximum above 183°C.

3. $-5^{\circ}C$ / $+0^{\circ}C$ allowable conditions.

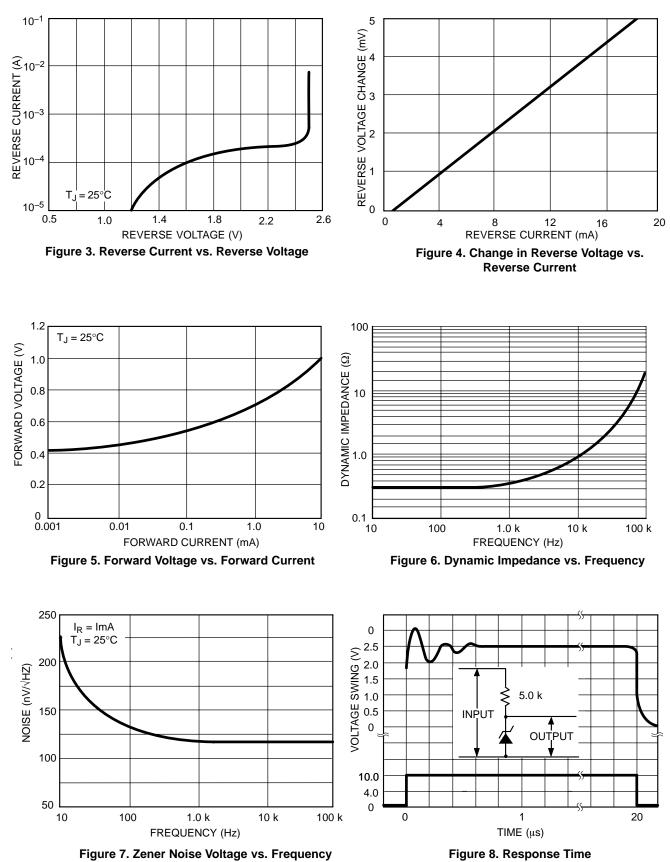
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise specified.)

Characteristic	Test Conditions		Min	Тур	Max	Unit
Reverse Breakdown Voltage	I _R = 1.0 mA		2.492	2.500	2.508	V
Reverse Breakdown Voltage	$-40^\circ C \leq T_A \leq 125^\circ C$		2.480	2.500	2.508	V
Reverse Breakdown Voltage Change with Current	400 μ A \leq I _R \leq 10 mA	(Note 4)		2.6 3.0	5.0 6.0	mV mV
Reverse Dynamic Impedance	I _R = 1.0 mA	(Note 4)		0.2 0.4	1.0 1.4	Ω Ω
Temperature Stability Average Temperature Coefficient	$\begin{array}{l} 0^{\circ}C \leq T_{A} \leq 70^{\circ}C, \ (\text{Note 5}) \\ 0^{\circ}C \leq T_{A} \leq 70^{\circ}C, \ (\text{Note 5}) \end{array}$			1.8 15		mV ppm/°C
Long Term Stabilty	$T_A = 25^{\circ}C \pm 0.1 \text{ C}, I_R = 1.0 \text{ mA}$		_	20	-	ppm/kHr

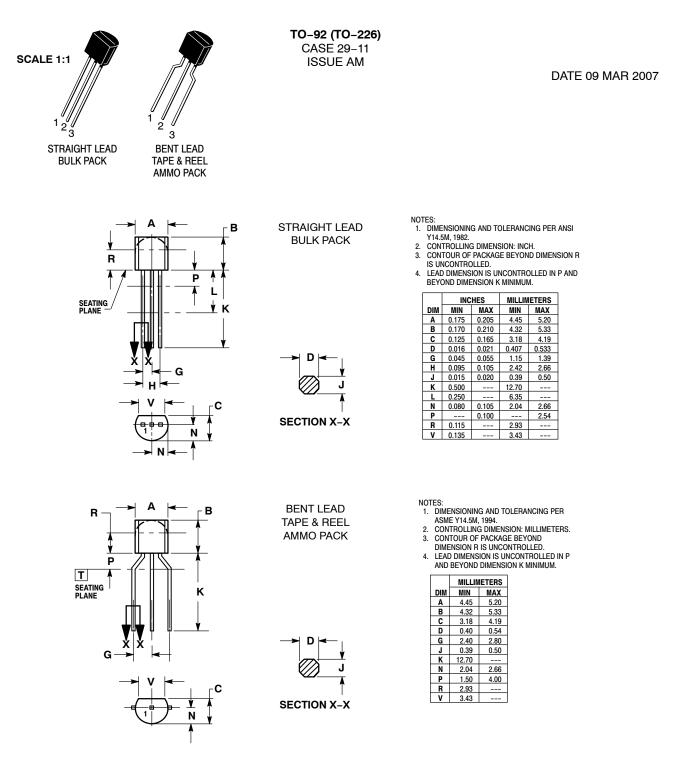
4. Denotes the specifications which apply over full operating temperature range.5. Average temperature coefficient is defined as the total voltage change divided by the specified temperature range.

NCV1009

TYPICAL PERFORMANCE CHARACTERISTICS



ONSEMI,



STYLES ON PAGE 2

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TO-92 (TO-226) CASE 29-11 **ISSUE AM**

STYLE 3: PIN 1. ANODE

DATE 09 MAR 2007

	EMITTER BASE COLLECTOR
STYLE 6: PIN 1. 2. 3.	SOURCE & SUBSTRATE
2.	ANODE CATHODE & ANODE CATHODE
2.	ANODE GATE CATHODE
2.	COLLECTOR EMITTER BASE
STYLE 26: PIN 1. 2. 3.	V _{CC} GROUND 2

	BASE EMITTER COLLECTOR
2.	SOURCE DRAIN GATE
2.	MAIN TERMINAL 1 Gate Main Terminal 2
2.	COLLECTOR BASE EMITTER
2.	SOURCE GATE DRAIN
STYLE 32: PIN 1.	BASE

2. COLLECTOR 3. EMITTER

	ANODE ANODE CATHODE
2.	DRAIN GATE SOURCE & SUBSTRATE
2.	3: ANODE 1 GATE CATHODE 2
2.	B: ANODE CATHODE NOT CONNECTED
2.	3: GATE SOURCE DRAIN
STYLE 2	B:

PIN 1. CATHODE ANODE
GATE

STYLE 33: PIN 1. RETURN 2. INPUT 3. OUTPUT

2.	CATHODE CATHODE ANODE
2.	BASE 1 EMITTER BASE 2
2.	EMITTER COLLECTOR BASE
2.	EMITTER COLLECTOR/ANODE CATHODE
2.	NOT CONNECTED ANODE CATHODE
2.	INPUT GROUND LOGIC

STYLE 5: PIN 1. DRAIN 2. SOURCE 3. GATE STYLE 10: PIN 1. CATHODE 2. GATE 3. ANODE STYLE 15: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 STYLE 20: PIN 1. NOT CONNECTED 2. CATHODE 3. ANODE STYLE 25: PIN 1. MT 1 2. GATE 3. MT 2 STYLE 30: PIN 1. DRAIN 2. GATE 3. SOURCE STYLE 35: PIN 1. GATE 2. COLLECTOR

3. EMITTER

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*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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SOIC-8 NB CASE 751-07 ISSUE AK

STYLE 1: PIN 1. EMITTER COLLECTOR 2. COLLECTOR 3. 4. EMITTER 5. EMITTER BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN З. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT 6. IOUT IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3 P-SOURCE P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE ANODE 2. SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. 8. CATHODE STYLE 22: PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC 4. I/O LINE 3 COMMON ANODE/GND 5. 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4. SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5. 6.

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. DRAIN, #2 4. GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. **MIRROR 1** STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. 8. LINE 1 OUT STYLE 27: PIN 1. ILIMIT 2 OVI 0 UVLO З. 4. INPUT+ 5. 6. SOURCE SOURCE SOURCE 7. 8 DRAIN

STYLE 4: PIN 1. 2. ANODE ANODE ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 BASE #2 З. COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 16 EMITTER, DIE #1 PIN 1. 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE EMITTER 2. 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE

6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW_TO_GND 2. DASIC OFF DASIC_SW_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK

7. VOULK 8. VIN

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SOURCE 1/DRAIN 2

7.

8. GATE 1

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7.

8

COLLECTOR, #1

COLLECTOR, #1

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